OKI semiconductor

MSM58321RS

REAL TIME CLOCK/CALENDAR

GENERAL DESCRIPTION

The MSM58321RS is a metal gate CMOS Real Time Clock/Calendar with a battery backup function for use in bus-oriented microprocessor applications.

The 4-bit bidirectional bus line method is used for the data I/O circuit; the clock is set, corrected, or read by accessing the memory.

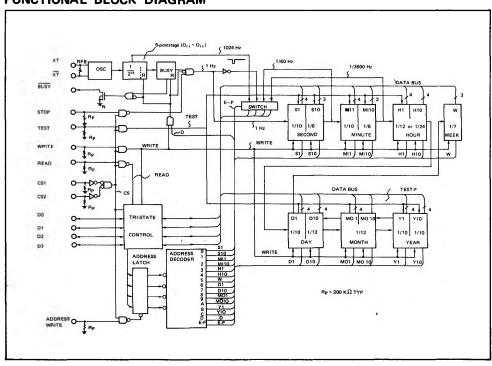
The time is read with 4-bit DATA I/O, ADDRESS WRITE, READ, and BUSY; it is written with 4-bit DATA I/O, ADDRESS WRITE, WRITE, and BUSY.

FEATURES

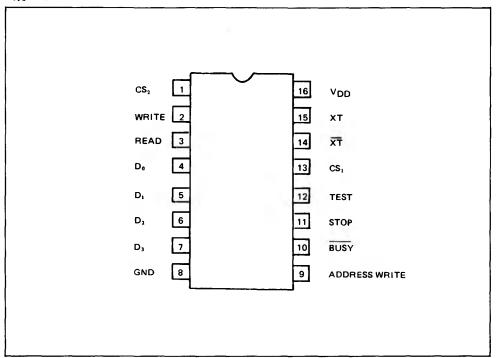
- 7 Function-Second, Minute, Hour, Day, Day-of-Week, Month, Year
- · Automatic leap year of calender
- 12/24 hour format
- Frequency divider 5-poststage reset
- · Busy circuit reset
- · Reference signal output

- 32.768KHz crystal controlled operation
- Single 5V power supply
- Bock-up battery operation to V_{CC} = 2.2V
- Low power dissipation
 90µW max. at V_{CC} = 3V
- 2.5mW max. at V_{CC} = 5V • 16 pin plastic DIP package

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



REGISTER TABLE

A		Addr	ess inpu	ıt	Register	C	eta i	nput/								
-	D _o	D, (A,)	D,	D, (A,)	Name	D.	р,	۵,	D ₃	Count value		ilue	Remarks			
0	0	0	0	0	S ₁	•	•	•	•	0	~	9				
1	1	٥	0	0	S,,		·	•		0	~	5	1			
2	0	1	0	0	Mi,	•	•	•	•	0	~	9	1			
3	1	1	0	0	MILO	•	•	•		0	~	5	1			
4	0	0	1	0	н,		•	•	•	0	~	9	1			
5	,	٥	1	0	Н, о				0	0~	1 or ()~2	D2 = 1 specifies PM, D2 D3 = 0 specifies 12-hou When D3 = 1 is written,	r time	r,	s AM, D3 = 1 specifies 24-hour timer, and reset inside the IC.
6	0	1	1	0	3	•	•	1		0	~	6				
7	1	1	1	0	D,	•	•	•	•	0	~	9	1			
8	0	0	0	1	D ₁ e	•	•	0	0	0	~	3	The D2 and D3 bits in D	10 ar	e used	to select a leap year.
9	1	0	0	1	MO,	Ŀ	·	·	·	0	~	9	Calendar	۵,	0,	Remainder obtained by dividing the year number by 4
A	0	1	0	1	MO, a	•				0	~	1	Gregorian calendar	0	0	0
В		1	0	1	Υ,	•		•	•	0	~	9	Showa	1_1_	0	3
С	0	0	1	1	Y10	١.		-	$\overline{}$	0	~	9	1	0	1	2
D E~F	0/1	0	1	1									circuit. They are reset and the WRITE input go A selector to obtain re	where to	es in to this 1.	he 1/2 ¹¹ frequency divider and the BUSY code is latched with ADDRESS LATCH at output, Reference signals are output to with ADDRESS LATCH and READ input

Notes: (1) There are no bits in blank fields for data input/output. O signals are output by reading and data is not stored by writing because there are no bits.

(2) The bit with marked ① is used to select the 12/24-hour timer and the bits marked ① are used to select a leap year. These three bits can be read or written

⁽³⁾ When signals are input to bus lines D0 - D3 and ADDRESS WRITE goes to 1 for address input, ADDRESS information is latched with ADDRESS LATCH.

■ PERIPHERALS · MSM58321RS ■-

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rating	Unit
Power voltage	V _{DD}	Ta = 25° C	−0.3 ~ 7	V
Input voltage	V _I	Ta = 25°C	GND-0.3V _{DD} + 0.3	V
Output voltage	v _O	Ta = 25° C	GND-0.3V _{DD} + 0.3	V
Storage temperature	Tstg	_	−55 ~ +150	°c

OPERATING CONDITIONS

Parameter	Symbol	Condition	Rating	Unit
Power voltage	V _{DD}	_	4.5 ~ 7	V
Date hold voltage	VDH	_	2.2 ~ 7	V
Crystal frequency	f(XT)	-	32.768	kHz
Operating temperature	Тор	_	−30 ~ +85	°c

Note: The data hold voltage guarantees the clock operations, though it does not guarantee operations outside the IC and data input/output.

DC CHARACTERISTICS

 $(V_{DD} = 5 V \pm 5\%, T_a = -30 \sim +85^{\circ}C)$

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
H input voltage	VIHI	- Note 1	3.6	_	_	v
n input voitage	V _{IH2}	- Note 2	V _{DD} −0.5	_	* -]
L input voltage	VIL	_	_	_	0.8	V
L output voltage	VOL	I _O = 1.6 mA		_	0.4	V
L output current	lOL	V _O = 0.4 V	1.6	_	_	mA
H input current	liH ₁	V ₁ = 5 V Note 3	10	25	50	110
n input current	IIH,	V _I = 5 V Note 4	_	_	1	μΑ
L input current	lIL.	V _I = 0 V	-	_	-1	μА
Input capacity	CI	f = 1 MHz	_	5	_	pF
Current consumption	IDD	f = 32.768 kHz V _{DD} = 5V/V _{DD} = 3V	-	100/15	500/30	μΑ

Note: 1. CS_2 , WRITE, READ, ADDRESS WRITE, STOP, TEST, $D_0 \sim D_3$

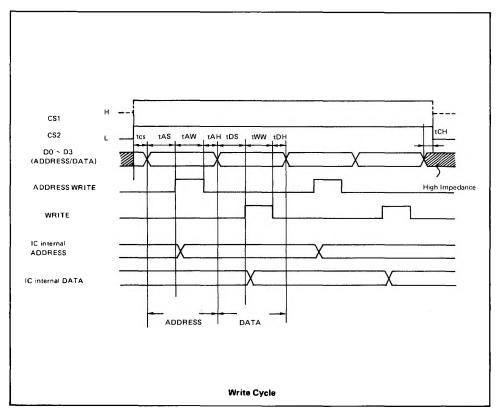
- 2. CS
- 3. CS1, CS2, WRITE, READ, ADDRESS WRITE, STOP, TEST
- 4. D₀ ~ D₃

SWITCHING CHARACTERISTICS

(1) WRITE mode

 $(V_{DD} = 5 V \pm 5\%, Ta = 25^{\circ}C)$

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
CS setup time	tCS	_	0	_	_	μs
CS Hold time	^t CH	ri a n	0	L. X	_	μs
Address setup time	tAS	_	0	U = U	_	με
Address write pulse width	^t AW	_	0.5	-	_	με
Address hold time	^t AH	_	0.1	_	_	μs
Data setup time	t _{DS}		0	_	_	μs
Write pulse width	tww	_	2		_	μs
Data hold time	tDH	_	0	_	_	μs



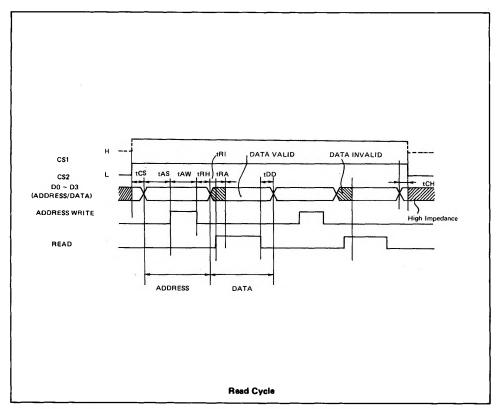
Note: ADDRESS WRITE and WRITE inputs are activated by the level, not by the edge.

(2) READ mode

 $(V_{DD} = 5 V \pm 5\%, Ta = 25^{\circ}C)$

Parameter	Symbol	Condition	Min.	Тур.	Ma×.	Unit
CS setup time	tCS		0	_	_	μs
CS Hold time	^t CH	_	0	_	_	μs
Address setup time	†AS	_	0	-	_	μs
Address write pulse width	tAW	_	0.5	_	_	μs
Address hold time	tAH	_	0.1	_	_	μs
Read access time	^t RA	_	_	-	see Note 1	μs
Read delay time	tDD	_	_	_	1	μs
Read inhibit time	†RI	_	0	_	_	μs

Note 1.
$$t_{RA} = 1 \mu s + CR \ln \left(\frac{V_{DD}}{V_{DD} - V_{1H} \min} \right)$$

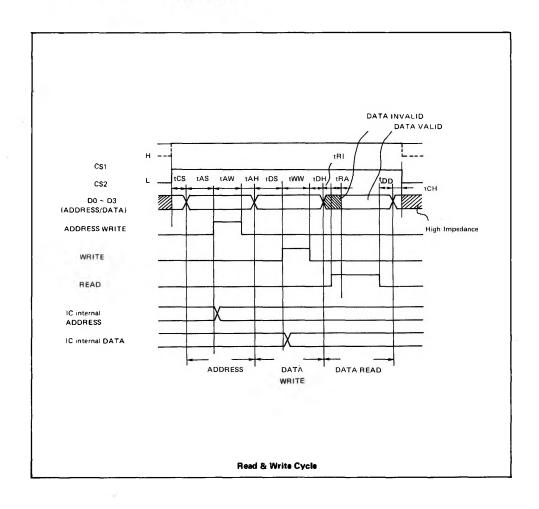


Note: ADDRESS WRITE and READ inputs are activated by the level, not by the edge.

(3) WRITE & READ mode

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
CS setup time	tCS	_	0	_	- 1	μs
CS hold time	tCH	<u>-</u>	0			μs
Address setup time	tAS		0		_	μs
Address write pulse width	tAW	_	0.5	_	_	μs
Address hold time	tAH	_	0.1	_	-	μs
Data setup time	tDS	_	0	_	_ [μs
Write pulse width	tww		2	_	_	μs
Data hold time	tDH	-	0	-		μs
Read access time	tRA	_		_	see Note 1	μs
Read delay time	tDD	_	_	_	1	μs
Read inhibit time	^t RI	-	0		_	μs

Note 1.
$$t_{RA} = 1 \mu_s + CR \ln \left(\frac{V_{DD}}{V_{DD} - V_{IH} \min} \right)$$



PIN DESCRIPTION

Name	Pin No.	Description
CS ₂	1	Chip select pins. These pins enable the interface with the external circuit when both of these pins are set at H level simultanuously.
CS ₁	13	If one of these pins is set at L level, STOP, TEST, WRITE, READ, ADDRESS WRITE pins and $D_0 \sim D_3$ pins are inactivated. Since the threshold voltage VT for the CS ₁ pin is higher than that for other pins, it should be connected to the detector of power circuit and peripherals and CS ₂ is to be connected to the microcontroller.
WRITE	2	WRITE pin is used to write data; it is activated when it is at the H level. Data bus data inside the IC is loaded to the object digit while this WRITE pin is at the H level, not at the WRITE input edge. Refer to Figure 2 below.
		WRITE DO S R DATA BL CS1 = CS2 = "H" DO H S1 WRITE F/F DO: Figure 2

Name	Pin No.	Descrip ²
READ	3	READ pin is used to read data; it is activated when it is at the H level. Address contents are latched with ADDRESS LATCH inside the IC at the D0 — D3 and ADDRESS WRITE pins to select the object digit, then an H-level signal is input to the READ pin to read data. If a count operation is continued by setting the STOP input to the L level, read operation must be performed, in principle, while the BUSY output is at the H level. While the BUSY output is at the L level, count operations are performed by digit counters and read data is not guaranteed, therefore, read operations are inhibited in this period. Figure 3 shows a time chart of the BUSY output, 1 Hz signal inside the IC, and READ input. A read operation is stopped temporarily within a period of 244 µs from the BUSY output trailing edge and it is restarted when the BUSY output goes to the H level again.
		The counter inside the IC starts counting at the I Hz signal leading edge. 1 Hz (inside IC) Read-enabled period Read-inhibited period Read operation is enabled in this period: however, it is used for program switching.
	(4)	If the counter operation is stopped by setting the STOP input to the H level, read operations are enabled regardless of the BUSY output. A read operation is enabled by microcomputer software regardless of the BUSY output during the counter operation by setting the STOP input to the L level. In this method, read operations are performed two or more times continuously and data that matches twice is used as guaranteed data.

Name	Pin No.	Description
D _{0S} ~ D ₃	4~7	Data input/output pins. (Bidirectional bus). The output is a open-drain type and 4.7 k Ω or higher pull-up registers are required utilize these pins as output pins.
GND	8	Ground pin.
ADDRESS WRITE	9	ADDRESS WRITE pin is used to load address information from the D0 – D3 I/O bus pins to the ADDRESS LATCH inside the IC; it is activated when it is at the H level. This input is activated by the level, not by the edge. Figure 4 show the relationships between the D0 address input, ADDRESS WRITE input, and ADDRESS LATCH input/output.
		(010
		IC inside Configuration" for the signal names.
		LATCH ausput
,		
		the CS1 and CS2 unless the D output of the ADDRESS DECODER inside the IC is H (CODE = H+L+H+H) and CS1 = CS2 = WRITE = H. Figure 6 shows the BUSY output time chart.
		Figure 6 shows the BUSY output time chart. Iperipheral circuit power 4.7 kΩ or more BUSY BUSY RESET WRITE BUSY The counter inside the IC starts counting at the
		the CS1 and CS2 unless the D output of the ADDRESS DECODER inside the IC is H (CODE = H+L+H+H) and CS1 = CS2 = WRITE = H. Figure 6 shows the BUSY output time chart. Peripheral circuit power SUSY
		the CS1 and CS2 unless the D output of the ADDRESS DECODER inside the IC is H (CODE = H+L+H+H) and CS1 = CS2 = WRITE = H. Figure 6 shows the BUSY output time chart. Iperipheral circuit power) 4.7 kΩ or more BUSY The counter inside the IC starts counting at the 1 Hz signal leading edge. 1 Hz (inside IC) 244μS 122μS 51μS Read/write-inhibited period

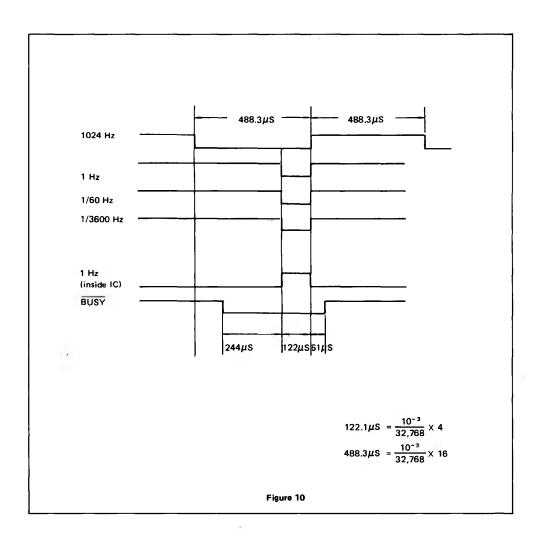
Name	Pin No.	Description
STOP	11	The STOP pin is used to input on/off control for a 1 Hz signal. When this pin goes to the H level, 1 Hz signals are inhbited and counting for all digits succeeding the S1 digit is stopped. When this pin goes to the L level, normal operations are performed; the digits are counted up. This STOP input controls stopping digit counting. Writing of external data in digits can be assured by setting the STOP input to the H level to stop counting, then writing sequentially from the low-order digits.
TEST	12	The TEST pin is used to test this IC; it is normally open or connected to GND. It is recommended to connect it to GND to safeguard against malfunctions from noise. The TEST pulse can be input to the following nine digits: S1, S10, MI10, H1, D1(W), M01, Y1 and Y10 When a TEST pulse is input to the D1 digit, the W digit is also counted up simultaneously. Input a TEST pulse as follows: Set the address to either digit explained above, then input a pulse to the TEST pin while CS1 = CS2 = STOP = H and WRITE = L. The specified and succeeding digits
		are counted up. (See Figure 7)
		1 Hz C1 C10 C10 C10 C10 C10 C10 C10 C10 C10
		0 - 9 0 - 6
		D1 Rp - 200 kΩ TYP Figure 7
		A digit is counted up at the leading edge (changing point from L to H) of a TEST pin input pulse. The pulse condition for TEST pin input at V_{DD} = 5 V \pm 5% is described in Figure 8 below.
		t _H = 10μS MIN t _L =10μS MIN
		Figure 8

Name	Pin No.	Description
XT XT	14 15	Oscillator pin. A 32,768K crystal oscillator, capacitors and trima condensor for frequency adjustment are to be connected as shown in Figure 8 below.
		GND or V _{DD} R _{FB} = 10 MΩ typ R _S = 200 KΩ typ R _S MSM58321RS X.TAL 32 768 kHz, The crystal impedance is 30 kΩ or less
		Figure 8
		If an external clock is to be used for MSM58321 RS's oscillation source, the external clock is to be input to XT, while \overline{XT} should be left open. Refer to the Figure 9 below.
		or +5V XT MSM58321RS
		Figure 9
V _{DD}	16	Power supply pin. Refer to the application circuit.

REFERENCE SIGNAL OUTPUT

Reference signals are output from the D0 - D3 pins under the following conditions:

Conditions	Output pin	Reference signal frequency	Pulse width	Output logic
WRITE = L	D ₀	1024 Hz	488.3 μs	Positive logic
READ = H	D ₁	1 Hz	122.1 μs	Negative logic
CS1 = CS2 = H	D ₂	1/60 Hz	122.1 µs	Negative logić
ADDRESS = E or F	D ₃	1/3600 Hz	122.1 µs	Negative logic



APPLICATION NOTES

READ mode

If CS1 = CS2 = H, WRITE = L, and READ = H, the ANALOG switch is in the OFF state. If data bus D0 is at the H level, the NOR gate output goes to L, N-channel MOSFET goes to OFF, and the D0 pin goes to the H level because it is pulled up to +5 V with the pull-up resistor; if it is at the L level, the NOR gate output goes to the H level, N-channel MOSFET goes to ON, therefore, the D0 pin goes to the L level. In the READ mode, four NAND gates connected to the D0-D3 pins are meaningless.

WRITE mode

If CS1 = CS2 = H, READ = L, and WRITE = H, the output of four NOR gates connected to the data buses goes to the L level and N-channel MOSFET goes to OFF. The ANALOG switch goes to ON and data information from the D0-D3 pins appear at the data buses via the NAND gate, INV gate, and ANALOG switch.

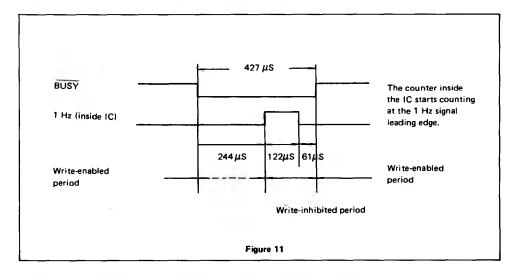
If the WRITE mode, the N-channel MOSFETs connected to the D0-D3 pins are meaningless because they are set OFF.

ADDRESS WRITE mode

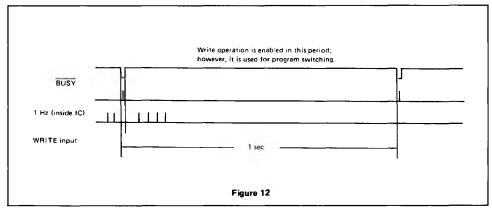
If CS1 = CS2 = H, WRITE = READ = L, and ADDRESS WRITE = H, the N-channel MOSFETs connected to the D0-D3 pins and the ANALOG switch connected to the data buses are set OFF. Address information input to the D0-D3 pins is loaded to the ADDRESS LATCH via the NAND gate with an ADDRESS WRITE signal. The output of ADDRESS latch is connected to the input of ADDRESS DECODER; the ADDRESS DECODER output is decided by the ADDRESS LATCH output.

WRITE and STOP

Note that the timing relationships between the STOP and WRITE inputs vary by the related digit when counting is stopped by the STOP input to write data. The time (t_{SH}) between the STOP input leading edge and WRITE input trailing edge for each digit is limited to the minimum value. (See Figure 11)



 $t_{SHS1} = 1 \ \mu_S$, $t_{SHS10} = 2 \ \mu_S$, $t_{SHM11} = 3 \ \mu_S$, $t_{SHM10} = 4 \ \mu_S$, $t_{SHM1} = 5 \ \mu_S$ $t_{SHH10} = 6 \ \mu_S$, $t_{SHD1} = 7 \ \mu_S$, $t_{SHW} = 7 \ \mu_S$, $t_{SHD10} = 8 \ \mu_S$, $t_{SHM01} = 9 \ \mu_S$ $t_{SHM010} = 10 \ \mu_S$, $t_{SHY1} = 11 \ \mu_S$, $t_{SHY10} = 12 \ \mu_S$. If a count operation is continued by setting the STOP input to the level, write operation must be performed, in principle, while the \overline{BUSY} output is at the H level. While the \overline{BUSY} output is at the L level, count operations are performed by the digit counters and write operation is inhibited, but there is a marginal period of 244 μ s from the \overline{BUSY} output trailing edge. If the \overline{BUSY} output goes to the L level during a write operation, the write operation is stopped temporarily within 244 μ s and it is restarted when the \overline{BUSY} output goes to the H level again. Figure 12 shows a time chart of \overline{BUSY} output, 1 Hz signal inside the IC, and WRITE, input.

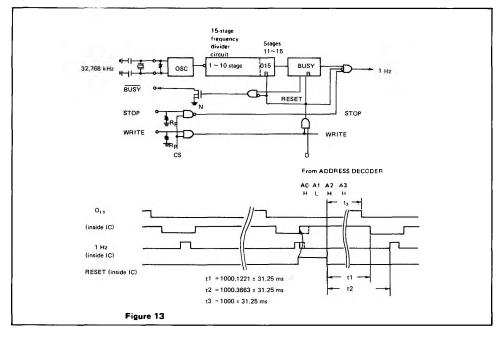


If the WRITE and READ inputs go to the H level simultaneously, the WRITE input has priority.

Frequency divider and BUSY circuit reset

If A0-A3 = H·L·H·H is input to ADDRESS DECODER, the DECODER output (D) goes to the H level. If CS1 = CS2 = H and WRITE = H in this state, the 5 poststages in the 15-stage frequency divider and the BUSY circuit are reset.

In this period, the \overline{BUSY} output remains at the H level and the 1 Hz signal inside the IC remains at the L level, and counting is stopped. If this reset is inactivated while the oscillator operates, the \overline{BUSY} output goes to the L level after 1000.1221 ± 31.25 ms and the 1 Hz signal inside the IC goes to the H level after 1000.3663 ± 31.25 ms. These times are not the same because the first ten stages in the 15-stage frequency divider are not reset. (See Figure 13)



Selection of leap year

This IC is designed to select leap year automatically.

Four types of leap years can be selected by writing a select signal in the D2 and D3 bits of the D10 digit (CODE = L·L·L·H). (See Table 1 for the functions.)

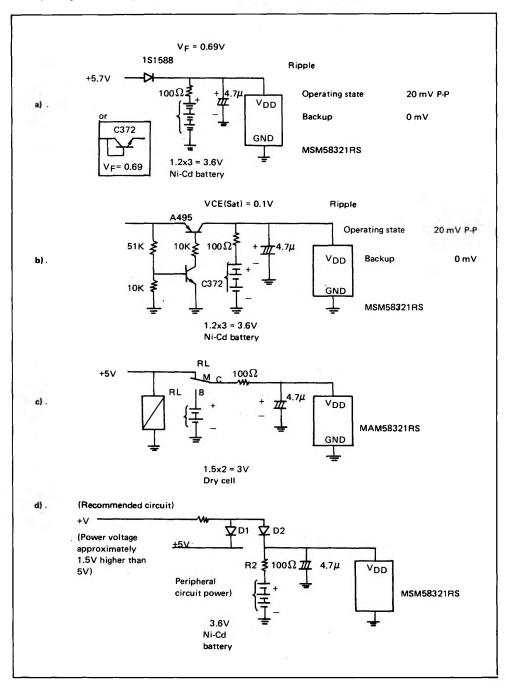
Gregorian calendar, Japanese Showa, or other calendars can be set arbitrarily in the Y1 and Y2 digits of this IC. There is a leap year every four years and the year number varies according to whether the Gregorian calendar or Showa is used. There are four combinations of year numbers and leap years. (See the Table below).

- No. 1: Gregorian calendar year. The remainder obtained by dividing the year number by 4 is 0.
- No. 2: Showa year. The remainder obtained by dividing the year number by 4 is 3.
- No. 3: The remainder obtained by dividing the year number by 4 is 2.
- No. 4: The remainder obtained by dividing the year number by 4 is 1.

No. 1 Calendar	D10 digit		Remainder obtained by	Loop years (everples)	
	Caleridai	D2	D3	dividing the year number by 4	Leap years (examples)
1	Gregorian	L	L	0	1980, 1984, 1988, 1992, 1996, 2000, 2004
2	Showa	н	L	3	(83) (87) (91) (95) (99) 55, 59, 63, 67, 71, 75, 79
3		L	Ħ	2	82, 86, 90, 94, 98, 102, 106
4		н	н	1	81, 85, 89, 93, 97, 101,105

APPLICATION CIRCUIT - POWER SUPPLY CIRCUIT

Open or ground unused pins (pins other than the XT, XT, D0-D3, and BUSY pins).



Note: Use the same diodes for D1 and D2 to reduce the level difference between +5V and V_{DD} of the MSM58321RS.